Features

- Two on chip PLLs. •
- Generates an EMI optimized clocking signal at output.
- Non Spread spectrum mode available •
- Input Frequency Range 2MHz– 200Mhz in Non Spread mode
- Input Frequency Range 6Mhz 80Mhz in ٠ Spread mode.
- Output Frequency Range 4Mhz 140Mhz.
- Four frequency outputs; two per PLL.
- Programmable spread range and type of modulation (center or down) and type of profile.
- Power down feature is incorporated.
- Both the PLL have reference frequency output.
- Supply voltage range 3.3 V (± 0.3)
- Software is available for configuring all the parameters of the Chip, through I2C.

Product Description

The AS80M2516A is dual phase lock loop clock chip. The AS80M2516A is a versatile spread spectrum frequency modulator design specifically for a wide range of clock frequencies. The AS80M2516A reduces electromagnetic interference (EMI) at clock source. The AS80M2516A allows significant system cost savings by reducing the number of circuit board layers and shielding that are required to pass EMI regulations.

The AS80M2516A is I2C configurable. All the

functional parameters of the AS80M2516A can be configured from external I2C master unit through I2C bus.

The AS80M2516A modulates the output of PLL in order to spread the bandwidth of a synthesized clock , there by decreasing the peak amplitudes of its harmonics. This results in significantly lower system EMI compared to the typical narrow band signal produced by oscillator and most clock generators. Lowering EMI by increasing a signal's bandwidth is called spread spectrum clock generation.

Pin Configuration



AS80M2516A

Alliance Semiconductor

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Block Diagram





Pin Description

Pin No	Pin Name	Pin Type	Description
1	X1IN	IN	Connection to Crystal-1
2	X1OUT	OUT	Connection to Crystal-1
3	VDDA/DIGITAL	PWR	Power supply to Analog and Digital blocks except the Output Buffers
4	VDD_FOUT2	PWR	Variable Output Voltage Control for FOUT2 . The minimum voltage is 1.8V.
5	VDD_FOUT1	PWR	Variable Output Voltage Control for FOUT1 . The minimum voltage is 1.8V.
6	FOUT1_CLK1	OUT	Tristatable Clock Output-1 of Clock Generator-1
7	FOUT2_CLK1	OUT	Tristatable Clock Output-2 of Clock Generator-1
8	PLL1_REF_D2	IN	Set High to divide the REF_IN(X1IN) by 2
9	POWERDOWN	IN	Powers the entire chip down
10	REF2OUT	OUT	Buffered and Divide by 2 Output of X1IN
11	FOUT2_CLK2	OUT	Tristatable Clock Output-2 of Clock Generator-2
12	FOUT1_CLK2	OUT	Tristatable Clock Output-1 of Clock Generator-2
13	SDA	IN/OUT	Serial Data I/O for I2C
14	SCL	IN	Serial Clock Input for I2C
15	GND	PWR	Ground to entire chip
16	REF1OUT	OUT	Buffered Output of X1IN

Note:- All the Pin types IN have CMOS pull-up resistors.



Absolute Maximum Ratings

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. These conditions represent a stress rating only, and functional operation of the device at these or any other conditions above the operational limits noted in this specification is not implied. Exposure to maximum rating conditions for extended conditions may affect device performance, functionality and reliability.

PARAMETER	SYMBOL	MIN	MAX	UNITS
Supply Voltage, dc (Vss = ground)	V _{DD}	V _{SS} -0.5	7	V
Input Voltage, dc	Vi	V _{SS} -0.5	V _{DD} +0.5	V
Output Voltage, dc	Vo	V _{SS} -0.5	V _{DD} +0.5	V
Input Clamp Current, dc (V _I < 0 or V _I >V _{DD})	I _{IK}	-50	50	mA
Output Clamp Current, dc (V ₁ < 0 or V ₁ $>$ V _{DD})	Ι _{οκ}	-50	50	mA
Storage Temperature Range (non condensing)	Τs	-65	150	°C
Ambient Temperature Range, Under Bias	T _A	-55	125	Ĵ
Junction Temperature	TJ		150	°C
Lead Temperature (soldering, 10s)			260	°C
Input Static Discharge Voltage Protection (MIL – STD 883E, Method 3015.7)			2	kV



CAUTION: ELECTROSTATIC SENSITIVE DEVICE

Permanent damage resulting in loss of functionality or performance may occur if this device is subjected to a high-energy electrostatic discharge.





Operating Conditions

PARAMETER	SYMBOL	CONDITIONS/DESCRIPTION	MIN	TYP	MAX	UNITS
Supply Voltage	V _{DD}	$3.3V \pm 10\%$	3	3.3	3.6	V
Ambient Operating Temperature Range	T _A		0		70	°C
Crystal Resonator Frequency	F _{XIN}		2		200	MHz
Serial Data Transfer Rate		Standard mode	10		100	kb/s
Output Driver Load Capacitance	CL				15	pF

Low Power EMI Reduction IC

Notice: The information in this document is subject to change without notice.

AS80M2516A



DC Electrical Specifications

Unless otherwise stated, V_{DD} =3.3V ± 10%, no load on any output, and ambient temperature range T_A =0°C to 70°C. Parameters with an astertsk (*) represent nominal characterization data and are not currently production tested to any specific limits. MIN and MAX characterization data are $\pm 3\sigma$ from typical. Negative currents inclicate current flows out of the device.

PARAMETER	SYMBOL	CONDITIONS/ DESCRIPTION	MIN	TYP	MAX	UNIT
Overall					·	
Supply Current, Dynamic	I _{DD}	V_{DD} =3.3V, F_{CLK} =50MHz, C_L =15pF		43		mA
Supply Current, Static	I _{DDL}	V _{DD} = 3.3V, powered down via Power Down pin		0.3		mA
All input pins					-	
High-Level Input Voltage	V _{IH}	V _{DD} =3.3V	2.0		V _{DD} +0.3	v
Low-Level Input Voltage	V _{IL}	V _{DD} =3.3V	V _{SS} -0.3		0.8	V
High-Level Input Current	I _{IH}		-1		1	μA
Low-Level Input Current (pull-up)	IIL		-20	-36	-80	μA
High-Level Output Source Current	I _{xOH}	V _{DD} =V(XIN) = 3.3V, V _O =0V	10	21	30	mA
Low-Level Output Source Current	I _{xOL}	V _{DD} =3.3V, V(XIN)=V _O =5.5V	-10	-21	-30	mA
Clock Outputs (CLK1,	CLK2)		-			
High-Level Output Source Current	I _{ОН}	V ₀ =2.4V		-20		mA
Low-Level Output Sink Current	I _{OL}	V ₀ =0.4V		23		mA
Output Impedance	Z _{OH}	$V_{O}=0.5V_{DD}$; output driving high		29		Ω
	Z _{OL}	Vo=0.5V _{DD} ; output driving low		27		



AC Timing Specifications

Unless otherwise stated, $V_{DD} = 3.3.0V \pm 10\%$, no load on any output, and ambient temperature range $T_A = 0^{\circ}C$ to 70°C. Parameters denoted with an asterisk (*) represent nominal characterization data and are not currently produciton tested to any specific limits. MIN and MAX characterization data are $\pm 3\sigma$ from typical.

PARAMETER	SYMBOL	CONDITIONS/ DESCRIPTION	CLOCK (MHz)	MIN	ТҮР	MAX	UNIT
Overall							
Output Frequency	f _o	V _{DD} = 3.3V		4		140	MHz
Rise Time	t _r	V _o = 0.3V to 3.0V; CL = 15pF			2.1		ns
Fall Time	T _f	V _O = 3.0V to 0.3V; CL = 15pF			1.9		ns
Clock Outputs (PL	L A clock via l	FOUT1_CLK1/FOUT2_CLK1 pins)	1	T	Γ		
Duty Cycle		Ratio of pulse width (as measured from rising edge to next falling edge at 2.5V) to one clock period	100	45		55	%
Jitter, Long Term	_	On rising edges 500 μ s apart at 2.5V relative to an ideal clock, C _L = 15pF, f _{XIN} =14.318MHz, F _{OUT} = 50MHz, PLL–B inactive.	100		45		
(σy(τ))*	Ι _{j(LT)}	On rising edges 500 μ s apart at 2.5V relative to an ideal clock, C _L = 15pF, f _{XIN} =14.318MHz, F _{OUT} = 50MHz, PLL –B active (60MHz)	50		165		
Jitter, Period	т	From rising edge to the next rising edge at 2.5V, C_L = 15pF, f_{XIN} =14.318MHz, F_{OUT} = 50MHz PLL-B inactive.	100		110		ps
(peak-peak)	Ι j(ΔΡ)	From rising edge to the next rising edge at 2.5V, CL = 15pF, f_{XIN} =14.318MHz, F_{OUT} = 50MHz PLL-B active (60MHz)	50		390		

AC Timing Specifications (Continued)

Unless otherwise stated, VDD = $3.3.0V \pm 10\%$, no load on any output, and ambient temperature range TA = 0°C to 70°C. Parameters denoted with an asterisk (*) represent nominal characterization data and are not currently produciton tested to any specific limits. MIN and MAX characterization data are $\pm 3\sigma$ from typical.

PARAMETER	SYMBOL	CONDITIONS/ DESCRIPTION	CLOCK (MHz)	MIN	ТҮР	MAX	UNIT
Clock Outputs (I	PLL B clock vi	a FOUT1_CLK2/FOUT2_CLK2 pi	ns)	<u>.</u>	1	1	
Duty Cycle		Ratio of pulse width (as measured from rising edge to next falling edge at 2.5V) to one clock period	100	45		55	%
Jitter, Long Term (σy(τ))*	T _{j(LT)}	On rising edges 500 μ s apart at 2.5V relative to an ideal clock, C _L = 15pF, f _{XIN} =14.318MHz, F _{OUT} = 50MHz , PLL –A inactive.	100		45		ps
		On rising edges 500 μ s apart at 2.5V relative to an ideal clock, $C_L = 15 \text{pF}$, $f_{XIN}=14.318 \text{MHz}$, $F_{OUT} = 50 \text{MHz}$, PLL –A active (60MHz)	60		75		
Jitter, Period (peak-peak)	$T_{j(\Delta P)}$	From rising edge to the next rising edge at 2.5V, $C_L = 15 pF$, $f_{XIN}=14.318 MHz$, $F_{OUT} = 50 MHz$ PLL-B inactive.	100		120		ps
		From rising edge to the next rising edge at 2.5V, $C_L = 15 pF$, $f_{XIN}=14.318 MHz$, $F_{OUT} = 50 MHz$ PLL-A active (50MHz)	60		400		
Clock Stabilization Time	t _{STB}	Otput active from power up, RUN Mode via Power Down pin			100		ns







Snapshot of 75MHz 0.75% Deviation Clock





rev 1.0 General I2C Serial Interface Information

The information in this section assumes familiarity with I2C programming.

How to Write through I2C :

- Master (host) sends a start bit.
- Master (host) sends the write address XX (H)
- AS80M2516A device will acknowledge
- Master (host) sends a dummy command code
- AS80M2516A device will acknowledge
- Master (host) sends a dummy byte count
- AS80M2516A device will acknowledge
- Master (host) starts sending first byte (Byte 0) through byte N - 1
- AS80M2516A device will acknowledge each byte one at a time.
- Master (host) sends a Stop bit

Controller (Host)	AS80M2516A (slave/receiver)
Start Bit	
Slave Address XX(H)	
	ACK
Dummy Command Code	
	ACK
Dummy byte count	
	ACK
First byte (Byte 0)	
	ACK
Second Byte (Byte 1)	
	ACK
Last Byte (Bye N-1)	
	ACK
Stop Bit	

How to Read through I2C:

- Master (host) will send start bit.
- Master (host) sends the read address XX (H)
- AS80M2516A device will acknowledge
- AS80M2516A device will send the byte count
- Master (host) acknowledges
- AS80M2516A device sends first byte (Byte 0) through byte N - 1
- Master (host) will need to acknowledge each byte
- Master (host) will send a stop bit (* N is the number of bytes)

Controller (Host)	AS80M2516A (slave/receiver)
Start Bit	
Slave Address XX(H)	
	ACK
	Date Byte Count
ACK	
	First byte (Byte 0)
ACK	
	Second Byte (Byte 1)
ACK	
	Last Byte (Bye N-1)
Not Acknowledge Stop Bit	

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Software

A demonstration board and software is available for the AS80M2516A. The software can operate under Windows 95 and Windows NT. The opening screen of the software is shown in figure 2. By pressing the drop down arrow of **Port ID** toolbar button ,any of the three parallel ports (LPT1 LPT2 or LPT3) can be selected. The selected parallel port is used for the I2C data transfer.

Opening screen



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rev 1.0 Programming the PLLs:-

Select the **CGEN check box** to enable the PLL and the EMI reduction check box to enable the spread spectrum on. Enter the input frequency (in Mhz), output frequency (Mhz), percentage error and modulation rate (Khz) in the respective input boxes.

To enable the OUT1 OUT2 and REFOUT click the respective check box. To tristate all the outputs click the tristate check box. Select the type of the modulation between the center or down and enter the deviation (percentage) in the respective input box. Profile type can be selected between the sine triangular or lexmark.

EMI reduction enable/disable option is only available for the PLL1.

Writing the data to the chip :-

There are two different ways of writing data to the chip.

1. Writing through the file.

2. Enter the required data in the respective forms and calculate and then write.

For Example:

CGEN Enable		
EMI Reduction	n	
General		
Input Frequency	15	Mhz
Out1 Frequency	65	Mhz
	1121	
Error (%)	0.01	
Error (%) Output Options —	0.01	
Error (%) Output Options	0.01	able
Error (%) Output Options OUT1 Enable	O.01	able
Error (%) Output Options OUT1 Enable Refout Enable Out2 Frequency	OUT2 Ena ✓ OUT2 Ena ✓ Tri State ✓ VCO/8	able
Error (%) Output Options — OUT1 Enable Refout Enable Out2 Frequency Spread Parameter	0.01 ✓ OUT2 End ✓ Tri State ✓ VCO/8	able
Error (%) Output Options — OUT1 Enable Refout Enable Out2 Frequency Spread Parameter O Down	0.01	able
Error (%) Output Options Output Options COUT1 Enable Out2 Frequency Spread Parameter Oown Deviation (%)	OUT2 End OUT2 End Tri State VCO/8 Center 0.75	able

- 1. Enter the input freq say 15 Mhz, in the **input frequency** box.
- 2. Enter the required output frequency say 65 Mhz, in the **out1 frequency** box.
- 3. Enter the percentage error say 0.01 in the **error** box.
- 4. Enter the modulation rate say 30 khz in the **modulation rate** box.
- Select the second output frequency by pressing the pull down menu of the out2 frequency.

The value of OUT2 frequency can be selected as vco/2, vco/3, vco/4, vco/5, vco/6, vco/8, vco/9, vco/10, vco/12, vco/15, vco/18, vco/24 or vco/30.

- Select the type of the deviation , percentage deviation and type of the profile.
- 7. Enter the data for PLL2 in a similar manner.



- 8. Press the **CalcResult** button to load the data in the ROM data panel.
- 9. To write this data to the chip press the I2CWrite button.

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Results Window

	VcoDivN	OutDivO	AbsErr
F	53	4	7.3359562800
	54	4	1.1737530048
	55	4	1.1150653545
	56	4	2.3475060096
	57	4	3.8146972656
	58	4	2.4061936598
	59	4	2.5235689603
	60	4	1.9953801081
	61	4	1.3498159555

CLK2 RESULTS SET						
	RefDivM	VcoDivN	Out2DivO	AbsErr		
	3	52	2	0		
	6	104	2	0		

Reading the data from the Chip

- 1. To read the data from the chip through I2C , press the **I2CRead** button.
- 2. The data can be seen in the rom data field.
- This data which is read from the chip can be saved in the file by clicking the Save button.



Package Information

16-PIN PLASTIC SMALL OUTLINE (SOIC) - NB (Narrow Body)

Package Type: 16HN





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